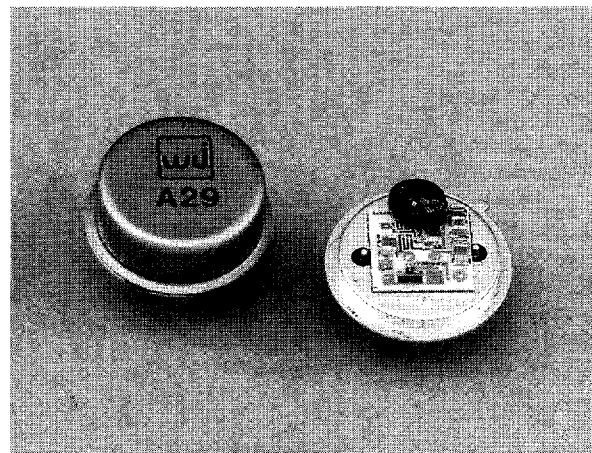


WJ-A29 / SMA29

10 to 1500 MHz TO-8 CASCADABLE AMPLIFIER

- ◆ AVAILABLE IN SURFACE MOUNT
- ◆ HIGH OUTPUT POWER: +22 dBm (TYP.)
- ◆ HIGH THIRD ORDER I.P.: +34 dBm (TYP.)
- ◆ WIDE POWER SUPPLY RANGE:
+10 TO +18 VOLTS



Specifications*

Characteristics	Typical	Guaranteed	
		0° to 50°C	-54° to +85°C
Frequency (Min.)	5-1700 MHz	10-1500 MHz	10-1500 MHz
Small Signal Gain (Min.)	6.5 dB	5.5 dB	5.0 dB
Gain Flatness (Max.)	±0.2 dB	±0.5 dB	±0.7 dB
Noise Figure (Max.)	9.0 dB	10.0 dB	10.5 dB
Power Output at 1 dB Compression (Min.)	+22.0 dBm	+20.0 dBm	+19.5 dBm
VSWR (Max.) Input/Output	< 1.7:1	2.0:1	2.0:1
DC Current (Max.) at 15 Volts	105 mA	107 mA	109 mA

*Measured in a 50-ohm system at +15 Vdc Nominal.

Notes:

1. WJ-CA29 is a standard WJ-A29 installed in a miniature SMA connector housing and guaranteed over 0°C to 50°C temperature range.

Typical Intermodulation Performance at 25°C

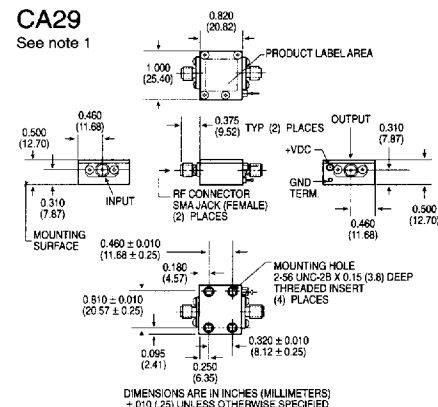
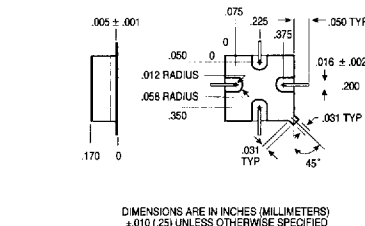
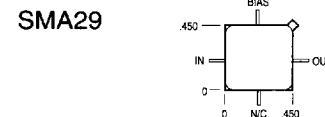
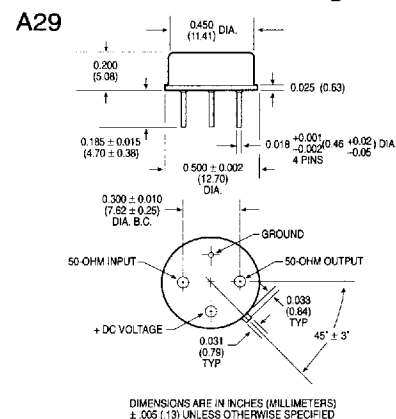
Second Order Harmonic Intercept point.....>+45 dBm (Typ.)
 Second Order Two Tone Intercept point>+40 dBm (Typ.)
 Third Order Two Tone Intercept Point.....+34 dBm (Typ.)

Absolute Maximum Ratings

Storage Temperature-62°C to +125°C
 Maximum Case Temperature125°C
 Maximum DC Voltage.....+18 Volts
 Maximum Continuous RF Input Power.....+19 dBm
 Maximum Short Term RF Input Power.....125 Milliwatts (1 Minute Max.)
 Maximum Peak Power0.5 Watt (3 µsec Max.)
 "S" Series Burn-In Temperature (Case)125°C

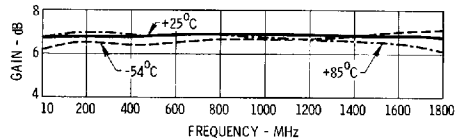
Weight approximately 2.0 grams (0.07 oz.)

Outline Drawings

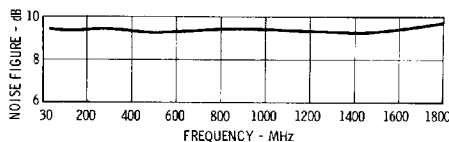


Typical Performance at 25°C

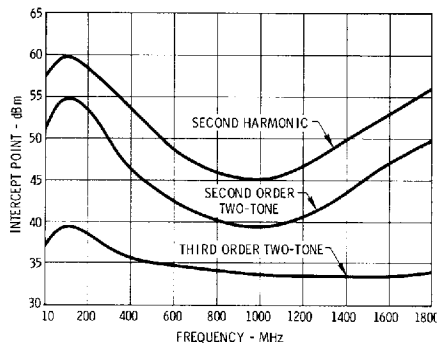
Gain



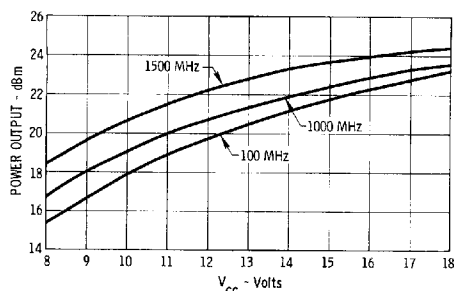
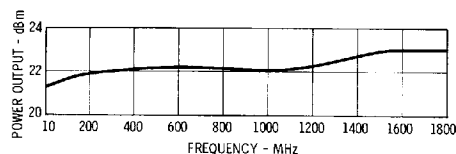
Noise Figure



Intercept Point

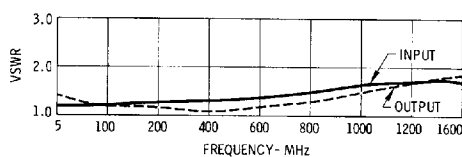


Power Output *



*at 1 dB Gain Compression

VSWR



Typical Automatic Test Data

V_{CC} = 15.0 V

Frequency MHz	VSWR IN	VSWR OUT	GAIN DB
2.0	1.6	1.9	6.1
5.0	1.3	1.4	6.4
10.0	1.2	1.3	6.5
50.0	1.2	1.2	6.6
100.0	1.2	1.2	6.5
200.0	1.2	1.2	6.4
300.0	1.2	1.2	6.4
400.0	1.2	1.1	6.5
500.0	1.2	1.1	6.7
600.0	1.3	1.1	6.8
700.0	1.3	1.1	6.9
800.0	1.3	1.1	6.9
900.0	1.3	1.2	7.0
1000.0	1.3	1.2	7.1
1100.0	1.3	1.3	7.1
1200.0	1.4	1.4	7.0
1300.0	1.4	1.4	6.9
1400.0	1.4	1.5	6.8
1500.0	1.5	1.5	6.7
1600.0	1.6	1.6	6.4
1700.0	1.9	1.6	6.0

Linear S-Parameters

Frequency MHz	S11		S21		S12		S22	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
2.0	.242	-94	2.020	-152	.197	32	.302	150
5.0	.121	-129	2.097	-170	.207	12	.152	152
10.0	.098	-150	2.113	-176	.209	6	.123	160
50.0	.092	-178	2.132	174	.212	-1	.103	165
100.0	.086	174	2.116	167	.212	-5	.099	159
200.0	.082	173	2.100	154	.211	-11	.089	144
300.0	.084	173	2.088	142	.212	-16	.076	132
400.0	.089	175	2.119	129	.214	-21	.056	128
500.0	.101	166	2.150	117	.213	-28	.042	133
600.0	.111	155	2.181	103	.213	-34	.033	150
700.0	.117	145	2.202	89	.211	-40	.038	173
800.0	.123	135	2.220	76	.211	-46	.059	178
900.0	.133	120	2.244	62	.212	-51	.083	169
1000.0	.145	99	2.254	48	.210	-58	.111	156
1100.0	.147	81	2.252	34	.210	-64	.136	142
1200.0	.157	53	2.245	20	.210	-70	.155	125
1300.0	.158	28	2.226	6	.211	-76	.175	106
1400.0	.172	-3	2.194	-10	.213	-82	.193	88
1500.0	.201	-37	2.155	-26	.217	-89	.206	68
1600.0	.242	-65	2.080	-42	.220	-97	.218	48
1700.0	.313	-93	1.999	-58	.223	-105	.221	31

Thermal Data: V_{CC} = 15 Vdc

Thermal Resistance θ_{JC} 45°C/W
 Transistor Power Dissipation P_d 0.031 W
 Junction Temperature Rise Above Case T_{Jc} ... 46°C